

P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
- 20	0.0073 at $V_{GS} = - 4.5$ V	- 20
	0.0090 at $V_{GS} = - 2.5$ V	- 18
	0.013 at $V_{GS} = - 1.8$ V	- 15

FEATURES

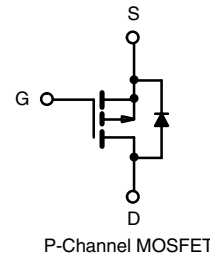
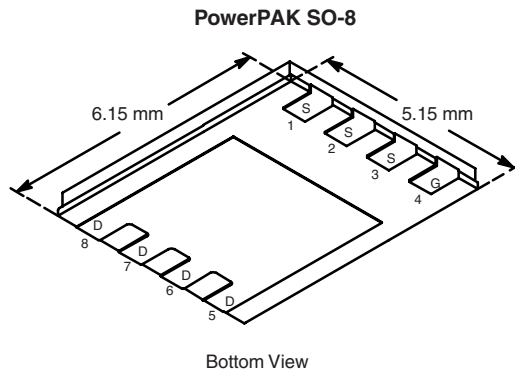
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFETs
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile



RoHS
COMPLIANT
HALOGEN
FREE
Available

APPLICATIONS

- Battery Switch for Portable Devices



Ordering Information: Si7485DP-T1-E3 (Lead (Pb)-free)
Si7485DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted					
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage	V_{DS}	- 20		V	
Gate-Source Voltage	V_{GS}	± 8			
Continuous Drain Current ($T_J = 150$ °C) ^a	I_D	$T_A = 25$ °C	- 20	- 12.5	A
		$T_A = 70$ °C	- 16.5	- 9.5	
Pulsed Drain Current	I_{DM}	- 50			
Continuous Source Current (Diode Conduction) ^a	I_S	- 4.5	- 1.6		
Maximum Power Dissipation ^a	P_D	$T_A = 25$ °C	5	1.8	W
		$T_A = 70$ °C	3.2	1.1	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b,c}		260			

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 10$ s	20	25	°C/W
		Steady State	54	68	
Maximum Junction-to-Case (Drain)	R_{thJC}	1.7	2.2		

Notes:

- Surface Mounted on 1" x 1" FR4 board.
- See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.



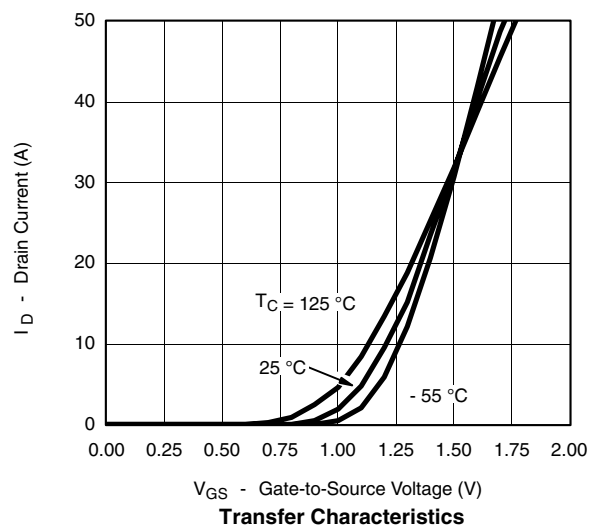
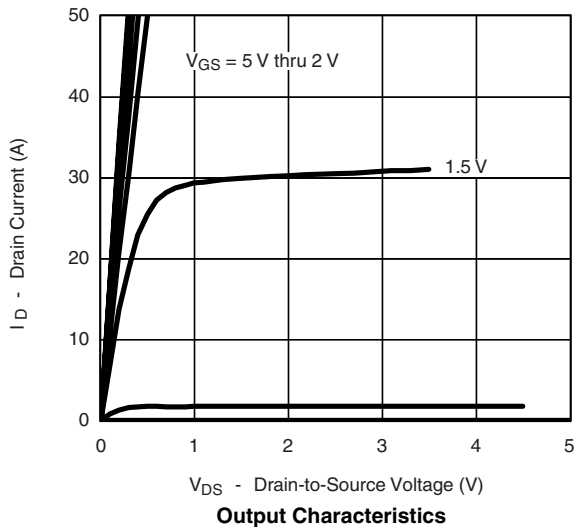
SPECIFICATIONS $T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -1\text{ mA}$	-0.4		-0.9	V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$			-1	μA
		$V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}, T_J = 70\text{ }^\circ\text{C}$			-10	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq -5\text{ V}, V_{GS} = -4.5\text{ V}$	-40			A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}, I_D = -20\text{ A}$		0.006	0.0073	Ω
		$V_{GS} = -2.5\text{ V}, I_D = -18\text{ A}$		0.0074	0.0090	
		$V_{GS} = -1.8\text{ V}, I_D = -15\text{ A}$		0.0106	0.013	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -15\text{ V}, I_D = -20\text{ A}$		80		S
Diode Forward Voltage ^a	V_{SD}	$I_S = -4.5\text{ A}, V_{GS} = 0\text{ V}$		-0.62	-1.1	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = -10\text{ V}, V_{GS} = -5\text{ V}, I_D = -20\text{ A}$		99	150	nC
Gate-Source Charge	Q_{gs}		11.5			
Gate-Drain Charge	Q_{gd}		29			
Gate Resistance	R_g			2.4		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\text{ V}, R_L = 10\text{ }\Omega$ $I_D \cong -1\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 6\text{ }\Omega$		80	120	ns
Rise Time	t_r		140	210		
Turn-Off Delay Time	$t_{d(off)}$		360	540		
Fall Time	t_f		170	260		
Source-Drain Reverse Recovery Time	t_{rr}		$I_F = -2.9\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}$		55	

Notes:

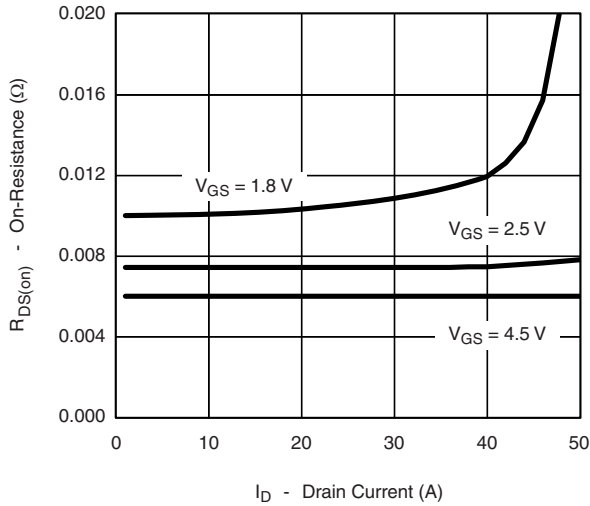
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

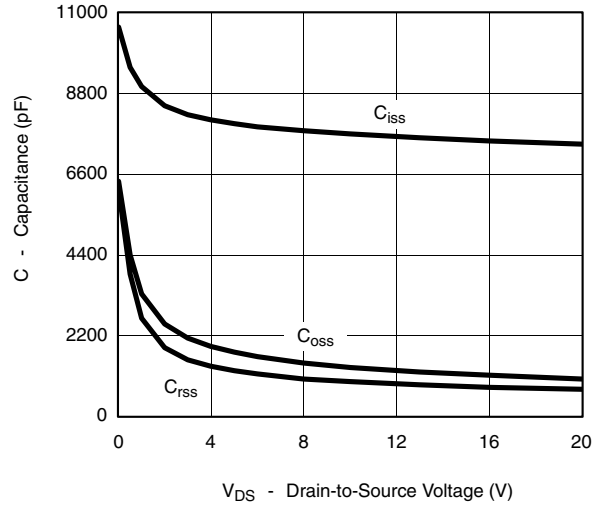
TYPICAL CHARACTERISTICS $25\text{ }^\circ\text{C}$, unless otherwise noted



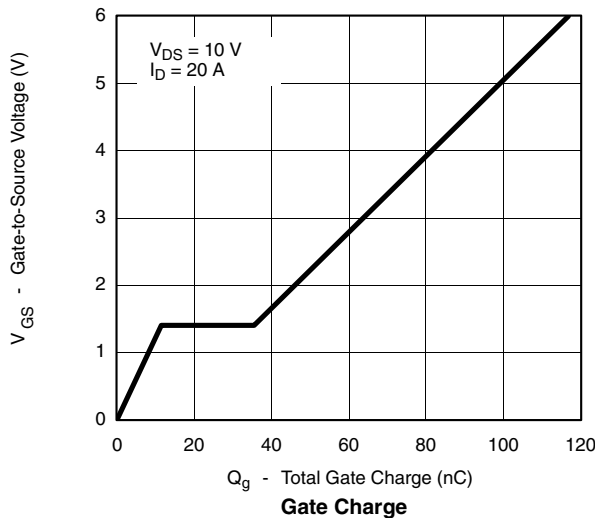
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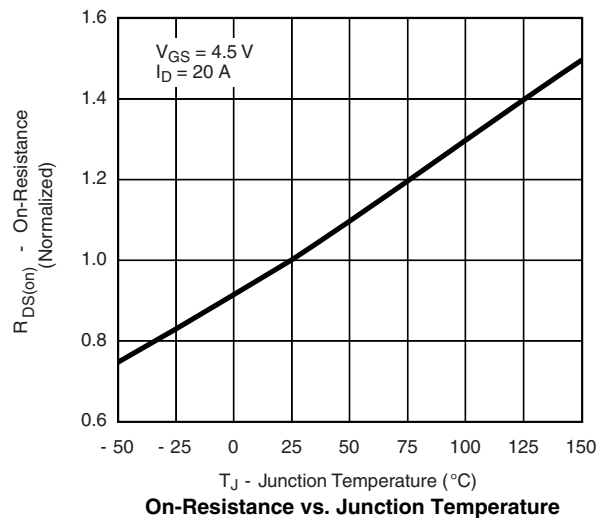
On-Resistance vs. Drain Current



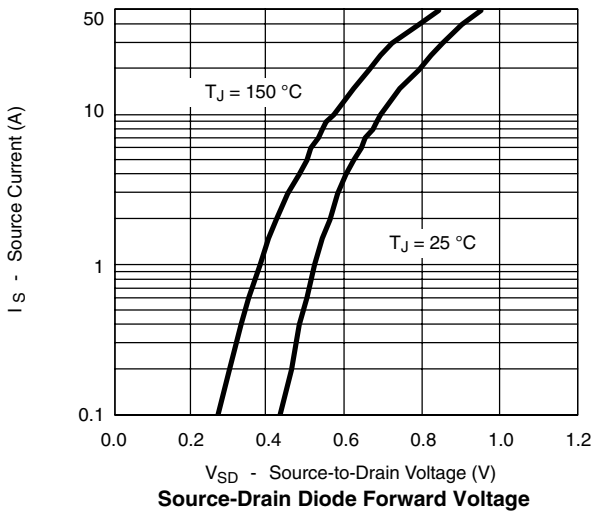
Capacitance



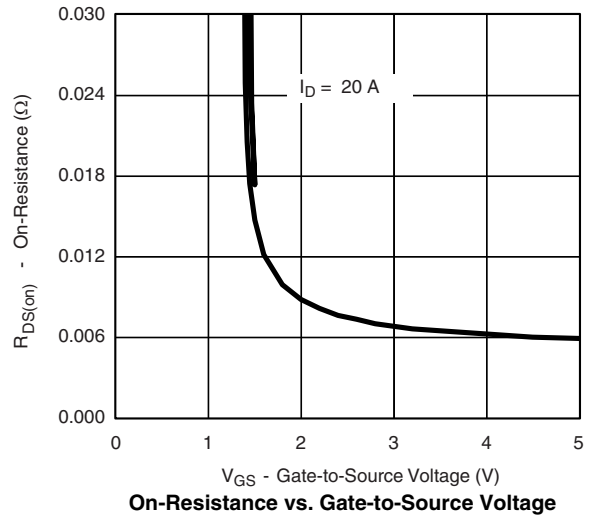
Gate Charge



On-Resistance vs. Junction Temperature

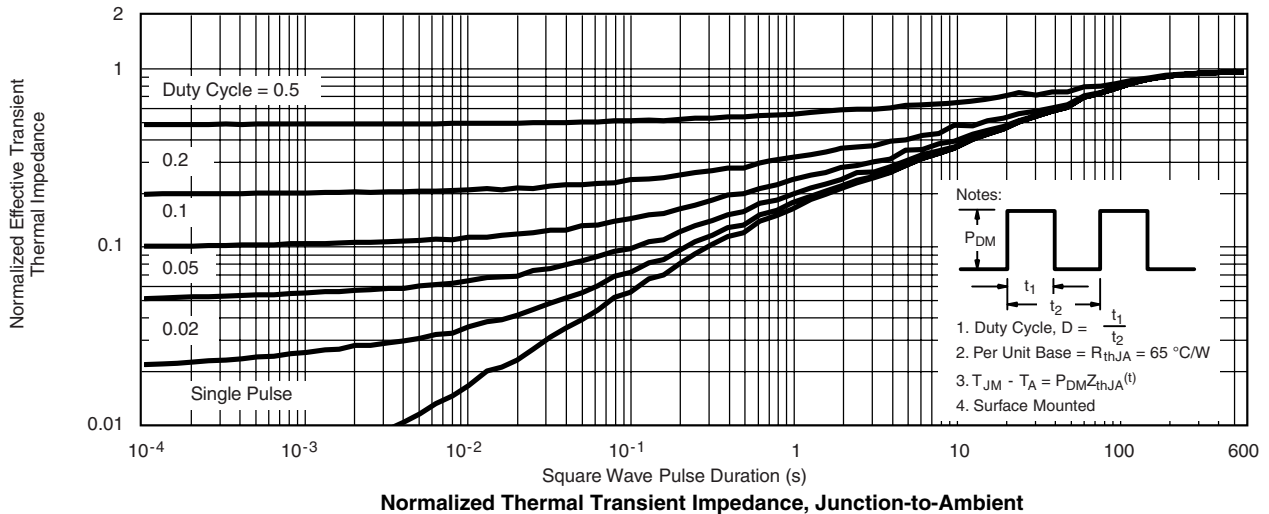
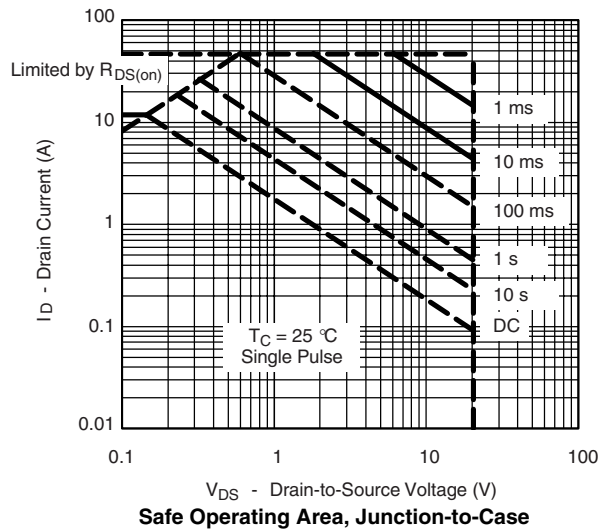
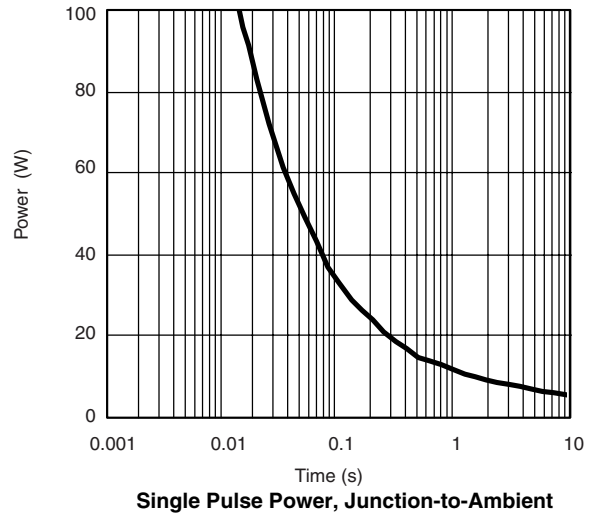
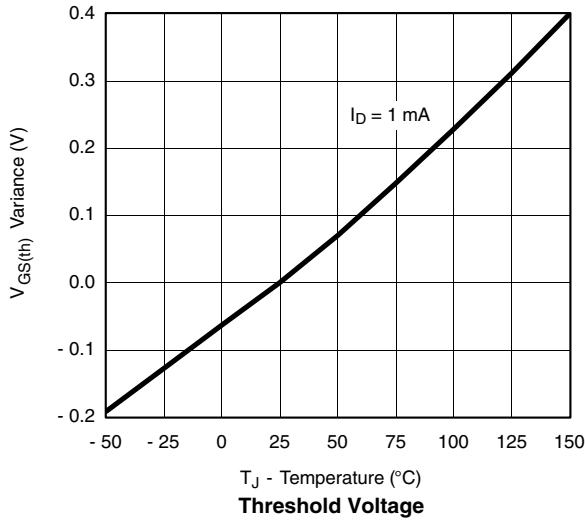


Source-Drain Diode Forward Voltage

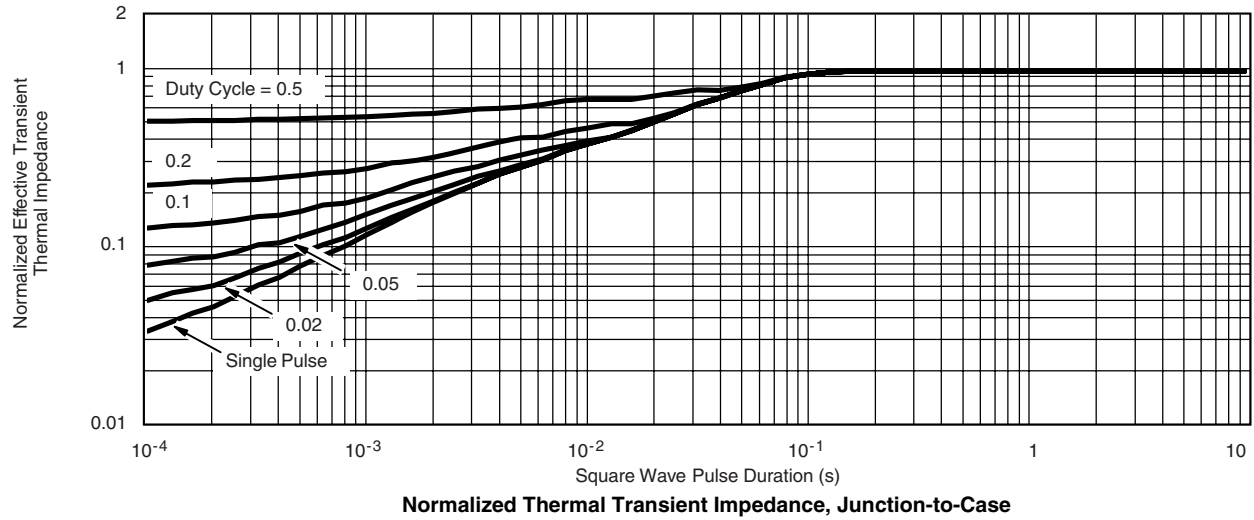


On-Resistance vs. Gate-to-Source Voltage

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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